

54F/74F821 10-Bit D-Type Flip-Flop

General Description

The 'F821 is a 10-bit D-type flip-flop with TRI-STATE® true outputs arranged in a broadside pinout. The 'F821 is functionally and pin compatible with the AMD's Am29821.

Features

- TRI-STATE Outputs
- Direct replacement for AMD's Am29821

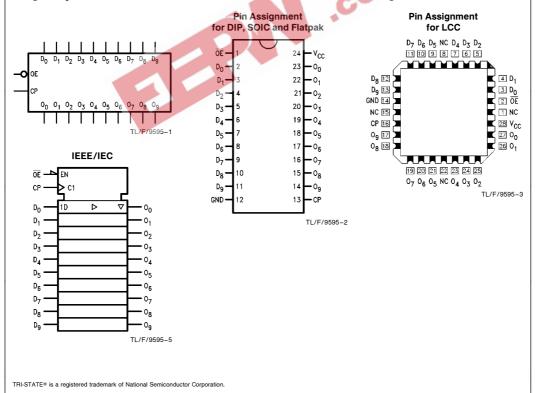
Commercial	Military	Package Number	Package Description		
74F821SPC		N24C	24-Lead (0.300" Wide) Molded Dual-In-Line		
	54F821SDM (Note 2)	J24F	24-Lead (0.300" Wide) Ceramic Dual-In-Line		
74F821SC (Note 1)		M24B	24-Lead (0.300" Wide) Molded Small Outline, JEDEC		
	54F821FM (Note 2)	W24C	24-Lead Cerpack		
	54F821LM (Note 2)	E28A	24-Lead Ceramic Leadless Chip Carrier, Type C		

Note 1: Devices also available in 13" reel. Use suffix = SCX.

 $\textbf{Note 2:} \ \textbf{Military grade device with environmental and burn-in processing.} \ \textbf{Use suffix} = \textbf{SDMQB, FMQB} \ \textbf{and} \ \textbf{LMQB.}$

Logic Symbols

Connection Diagrams



Unit Loading/Fan Out

		54F/74F					
Pin Names	Description	U.L. HIGH/LOW	Input I _{IH} /I _{IL} Output I _{OH} /I _{OL}				
D ₀ -D ₉	Data Inputs	1.0/1.0	20 μA/ – 0.6 mA				
ŌĒ	Output Enable TRI-STATE Input	1.0/1.0	20 μA/ - 0.6 mA				
CP	Clock Input	1.0/1.0	20 μA/ -0.6 mA				
O ₀ -O ₉	TRI-STATE Outputs	150/40 (33.3)	-3.0 mA/24 mA (20 mA)				

Functional Description

The 'F821 consists of ten D-type edge-triggered flip-flops. This device has TRI-STATE true outputs for bus systems organized in a broadside pinning. The buffered Clock (CP) and buffered Output Enable ($\overline{\text{OE}}$) are common to all flipflops. The flip-flops will store the state of their individual D inputs that meet the setup and hold times requirements on the LOW-to-HIGH CP transition. With the $\overline{\text{OE}}$ LOW the content of the flip-flops are available at the outputs. When the $\overline{\text{OE}}$ is HIGH, the outputs go to the high impedance state. Operation of the OE input does not affect the state of the flip-flops.

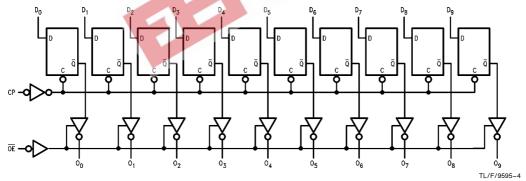
Function Table

Inputs		Internal Outpu		Function					
ŌĒ	СР	D	Q	0	T unotion				
Н	Н	Χ	NC	Z	Hold				
Н	L	Χ	NC	Z	Hold				
Н		L	Н	Z	Load				
Н		Н	L	Z	Load				
L		L	Н	L «	Data Available				
L	_	Н	L	a H∯-	Data Available				
L	Н	Χ	NC	NC	No Change in Data				
Ĺ	L	X	NC	NC	No Change in Data				

- LOW Voltage Level
 HIGH Voltage Level
 Immaterial

- High Impedance
 = LOW-to-HIGH Transition
- = No Change

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

 $\begin{array}{lll} \mbox{Storage Temperature} & -65^{\circ}\mbox{C to} + 150^{\circ}\mbox{C} \\ \mbox{Ambient Temperature under Bias} & -55^{\circ}\mbox{C to} + 125^{\circ}\mbox{C} \\ \mbox{Junction Temperature under Bias} & -55^{\circ}\mbox{C to} + 175^{\circ}\mbox{C} \\ \mbox{Plastic} & -55^{\circ}\mbox{C to} + 150^{\circ}\mbox{C} \\ \end{array}$

 $\begin{array}{lll} \text{V}_{\text{CC}} \text{ Pin Potential to} \\ \text{Ground Pin} & -0.5 \text{V to } +7.0 \text{V} \\ \text{Input Voltage (Note 2)} & -0.5 \text{V to } +7.0 \text{V} \\ \text{Input Current (Note 2)} & -30 \text{ mA to } +5.0 \text{ mA} \\ \end{array}$

Voltage Applied to Output in HIGH State (with V_{CC} = 0V)

 $\begin{array}{lll} \text{Standard Output} & -0.5 \text{V to V}_{\text{CC}} \\ \text{TRI-STATE Output} & -0.5 \text{V to } +5.5 \text{V} \end{array}$

Current Applied to Output

in LOW State (Max) twice the rated I_{OL} (mA)

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

Free Air Ambient Temperature

Supply Voltage

 Military
 + 4.5V to + 5.5V

 Commercial
 + 4.5V to + 5.5V

DC Electrical Characteristics

Symbol	Parameter		54F/74F		Units	V _{CC}	Conditions		
Cymbol	raidine		Min	Тур	Max 🎻	19	VCC	Conditions	
V _{IH}	Input HIGH Voltage		2.0		26	V	400	Recognized as a HIGH Signal	
V _{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal	
V _{CD}	Input Clamp Diode Vo	ltage			-1.2	V	Min	$I_{\text{IN}} = -18 \text{mA}$	
V _{OH}	Output HIGH Voltage	54F 10% V _{CC} 54F 10% V _{CC} 74F 10% V _{CC} 74F 10% V _{CC} 74F 5% V _{CC} 74F 5% V _{CC}	2.5 2.4 2.5 2.4 2.7 2.7			V	Min	$\begin{split} I_{OH} &= -1 \text{ mA} \\ I_{OH} &= -3 \text{ mA} \\ I_{OH} &= -1 \text{ mA} \\ I_{OH} &= -3 \text{ mA} \\ I_{OH} &= -1 \text{ mA} \\ I_{OH} &= -3 \text{ mA} \\ \end{split}$	
V _{OL}	Output LOW Voltage	54F 10% V _{CC} 74F 10% V _{CC}			0.5 0.5	V	Min	$I_{OL} = 20 \text{ mA}$ $I_{OL} = 24 \text{ mA}$	
I _{IH}	Input HIGH Current	54F 74F			20.0 5.0	μΑ	Max	V _{IN} = 2.7V	
I _{BVI}	Input HIGH Current Breakdown Test	54F 74F			100 7.0	μΑ	Max	V _{IN} = 7.0V	
I _{CEX}	Output HIGH Leakage Current	54F 74F			250 50	μΑ	Max	$V_{OUT} = V_{CC}$	
V _{ID}	Input Leakage Test	74F	4.75			٧	0.0	$I_{\text{ID}} = 1.9 \mu\text{A},$ All Other Pins Grounded	
I _{OD}	Output Leakage Circuit Current	74F			3.75	μΑ	0.0	V _{IOD} = 150 mV All Other Pins Grounded	
I _{IL}	Input LOW Current				-0.6	mA	Max	V _{IN} = 0.5V	
lozh	Output Leakage Current				50	μΑ	Max	V _{OUT} = 2.7V	
I _{OZL}	Output Leakage Current				-50	μΑ	Max	$V_{OUT} = 0.5V$	
I _{OS}	Output Short-Circuit Current		-60		-150	mA	Max	V _{OUT} = 0V	
Iccz	Power Supply Current			78	100	mA	Max	V _O = HIGH Z	

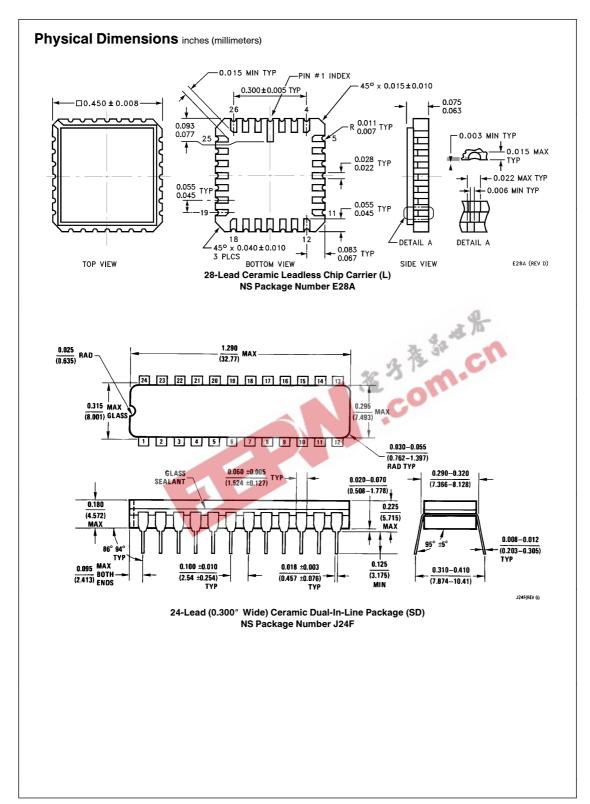
AC Electrical Characteristics

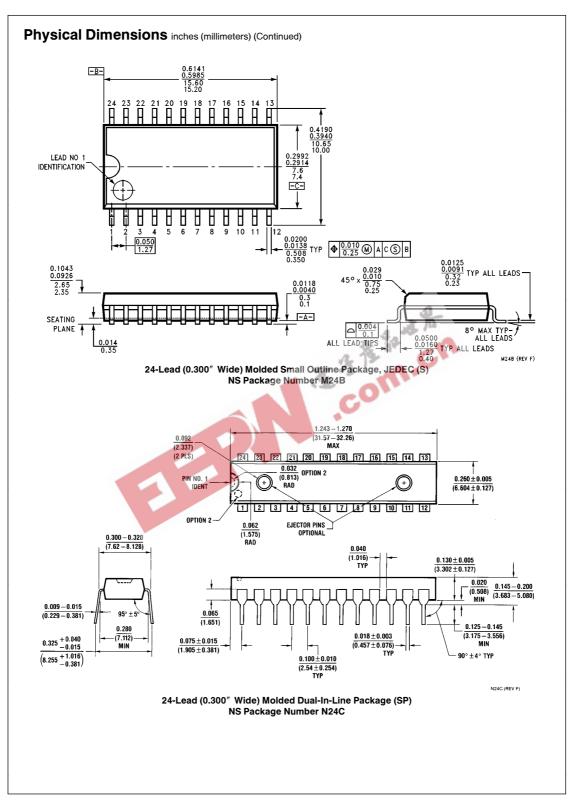
		$74F$ $T_{A} = +25^{\circ}C$ $V_{CC} = +5.0V$ $C_{L} = 50 \text{ pF}$			54F T _A , V _{CC} = Mil C _L = 50 pF		$74F$ $T_{A}, V_{CC} = Com$ $C_{L} = 50 \text{ pF}$		Units
Symbol	Parameter								
		Min	Тур	Max	Min	Max	Min	Max	
f _{max}	Maximum Clock Frequency	100	150		60		70		MHz
t _{PLH}	Propagation Delay CP to O _n	2.0 2.0	6.4 6.2	9.5 9.5	2.0 2.0	10.5 10.5	2.0 2.0	10.5 10.5	ns
t _{PZH}	Output Enable Time OE to On	2.0 2.0	5.8 6.3	10.5 10.5	2.0 2.0	13.0 13.0	2.0 2.0	11.5 11.5	ns
t _{PHZ}	Output Disable Time OE to On	1.5 1.5	3.4 3.5	7.0 7.0	1.0 1.0	7.5 7.5	1.5 1.5	7.5 7.5	113

AC Operating Requirements

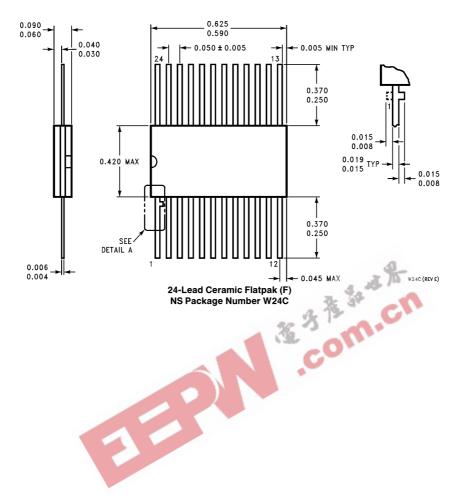
		$74F$ $T_A = +25^{\circ}C$ $V_{CC} = +5.0V$		5	4F	74F	Units
Symbol	Parameter			T _A , V _C	cc = Mil	$T_A,V_CC=Com$	
		Min	Max	Min	Max	Min Max	
t _s (H) t _s (L)	Setup Time, HIGH or LOW D_n to CP	2.5 2.5		4.0 4.0	- X	3.0 3.0	ns
t _h (H)	Hold Time, HIGH or LOW D _n to CP	2.5 2.5		2.5 2.5	8 3	2 .5 2.5	
t _w (H)	CP Pulse Width HIGH or LOW	5.0 5.0		6.0 6.0	CO	6.0 6.0	ns

Ordering Information The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows: <u>821</u> <u>74F</u> Temperature Range Family Special Variations 74F = Commercial FAST 54F = Military FAST QB = Military grade device with environmental and burn-in processing Device Type X = Devices ship in 13" reel Package Code Temperature Range C=Commercial (0°C to +70°C) M=Military (-55°C to +125°C) SP = Slim Plastic DIP SD = Slim Ceramic DIP F = Flatpak Leadless Chip Carrier (LCC) Small Outline (SOIC) L = s =





Physical Dimensions inches (millimeters) (Continued)



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